



UGFZ10A . . . 10G Series

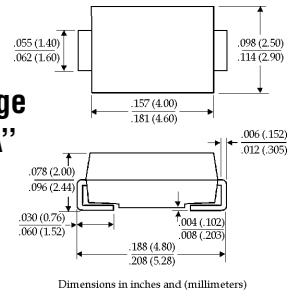
Description



OWIE™
INSIDE

Mechanical Dimensions

Package
"SMA"



Features

- **LOWEST COST FOR GLASS SINTERED ULTRA - FAST CONSTRUCTION**
- **LOWEST V_F FOR GLASS SINTERED ULTRA - FAST CONSTRUCTION**
- **TYPICAL $I_R < 100$ nAmps**
- **1.0 AMP OPERATION @ $T_A = 55^\circ\text{C}$, WITH NO THERMAL RUNAWAY**
- **SINTERED GLASS CAVITY-FREE JUNCTION**

Electrical Characteristics @ 25°C.

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Units

Maximum Ratings	10A	10B	10D	10G	Units
Peak Repetitive Reverse Voltage... V_{RRM}	50	100	200	400	Volts
RMS Reverse Voltage... $V_{R(rms)}$	35	70	140	280	Volts
DC Blocking Voltage... V_{DC}	50	100	200	400	Volts
Average Forward Rectified Current... $I_{F(av)}$ @ $T_A = 55^\circ\text{C}$ (Note 2)	1.0				Amps
Non-Repetitive Peak Forward Surge Current... I_{FSM} ½ Sine Wave Superimposed on Rated Load	30				Amps
Forward Voltage @ 1.0A... V_F	< 0.95 >			1.25	Volts
Full Load Reverse Current... $I_R(av)$ Full Cycle Average @ $T_A = 135^\circ\text{C}$	30				µAmps
DC Reverse Current... $I_{R(max)}$ @ Rated DC Blocking Voltage	$T_A = 25^\circ\text{C}$	5.0			µAmps
	$T_A = 150^\circ\text{C}$	200			µAmps
Typical Thermal Resistance... $R_{\theta JA}$ (Note 2)	45				°C/W
Maximum Reverse Recovery Time... t_{RR} (Note 3)	35				nS
Operating & Storage Temperature Range... T_J, T_{STRG}	-65 to 175				°C

- NOTES:**
1. Measured @ 1 MHz and applied reverse voltage of 4.0V.
 2. 5.0mm² (.013mm thick) land areas.
 3. Reverse Recovery Condition $I_F = 0.5A$, $I_R = 1.0A$, $I_{RR} = 0.25A$.